

Vishay Semiconductors

High Voltage Surface Mount Input Rectifier Diode, 20 A



PRIMARY CHARACTERISTICS					
I _{F(AV)} 20 A					
V _R	800 V, 1200 V				
V _F at I _F	1.1 V				
I _{FSM}	300 A				
T _J max.	150 °C				
Package	D ² PAK (TO-263AB)				
Circuit configuration	Single				

FEATURES

- Glass passivated pellet chip junction
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C



HALOGEN

FREE

- \bullet Designed and qualified according to JEDEC $^{\textcircled{B}}\text{-}JESD$ 47
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- Input rectification
- Vishay Semiconductors switches and output rectifiers which are available in identical package outlines

DESCRIPTION

The VS-20ETS...S-M3 rectifier High Voltage Series has been optimized for very low forward voltage drop, with moderate leakage. The glass passivation technology used has reliable operation up to 150 $^{\circ}$ C junction temperature.

OUTPUT CURRENT IN TYPICAL APPLICATIONS						
APPLICATIONS	SINGLE-PHASE BRIDGE THREE-PHASE BRIDGE UNITS					
Capacitive input filter $T_A = 55 \text{ °C}$, $T_J = 125 \text{ °C}$ common heatsink of 1 °C/W	16.3	21	А			

MAJOR RATINGS AND CHARACTERISTICS							
SYMBOL CHARACTERISTICS VALUES UNITS							
I _{F(AV)}	Sinusoidal waveform	20	A				
V _{RRM}		800/1200	V				
I _{FSM}		300	A				
V _F	20 A, T _J = 25 °C	1.1	V				
TJ		-40 to +150	°C				

VOLTAGE RATINGS							
PART NUMBER V _{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V		V _{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I _{RRM} AT 150 °C mA				
VS-20ETS08S-M3	800	900	1				
VS-20ETS12S-M3	1200	1300	I				

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS			
Maximum average forward current	I _{F(AV)}	T_{C} = 105 °C, 180° conduction half sine wave	20				
Maximum peak one cycle		10 ms sine pulse, rated V _{RRM} applied	250	A			
non-repetitive surge current	I _{FSM}	10 ms sine pulse, no voltage reapplied	300				
Maximum I ² t for fusing	l ² t	10 ms sine pulse, rated V _{RRM} applied	316	A ² s			
Maximum 1-t for fusing	1-1	10 ms sine pulse, no voltage reapplied 442		A-2			
Maximum I ² \sqrt{t} for fusing	l²√t	t = 0.1 ms to 10 ms, no voltage reapplied	4420	A²√s			

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VS-20ETS08S-M3, VS-20ETS12S-M3 Series

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ELECTRICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST	CONDITIONS	VALUES	UNITS		
Maximum forward voltage drop	V _{FM}	20 A, T _J = 25 °C		1.1	V		
Forward slope resistance	r _t	T _J = 150 °C		10.4	mΩ		
Threshold voltage	V _{F(TO)}			0.85	V		
Maximum reverse leakage current		T _J = 25 °C	V _B = Rated V _{BBM}	0.1	mA		
Maximum reverse leakage current	IRM	T _J = 150 °C	VR = naleu VRRM	1.0	ША		

THERMAL - MECHANICAL SPECIF	ICATIONS	5		
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature rang	e T _J , T _{Stg}		-40 to +150	°C
Maximum thermal resistance, junction to case	R _{thJC}	DC operation	1.3	
Maximum thermal resistance, junction to ambient	R _{thJA} ⁽¹⁾	For D ² PAK version	62	°C/W
Typical thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, and greased	0.5	
Approximate weight			2	g
Approximate weight			0.07	oz.
Mounting torque			6.0 (5.0)	kgf · cm
maximum			12 (10)	(lbf · in)
Marking davias		Case style D ² PAK (TO-263AB)	20ETS08S	
Marking device		Case Sigle D-FAR (IO-203AB)	20ET	S12S

Note

⁽¹⁾ When mounted on 1" square (650 mm²) PCB of FR-4 or G-10 material 4 oz. (140 μm) copper 40 °C/W For recommended footprint and soldering techniques refer to application note #AN-994

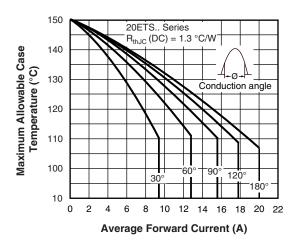


Fig. 1 - Current Rating Characteristics

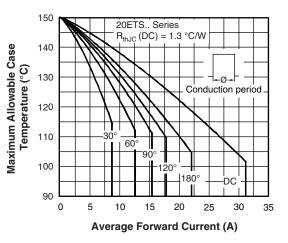


Fig. 2 - Current Rating Characteristics



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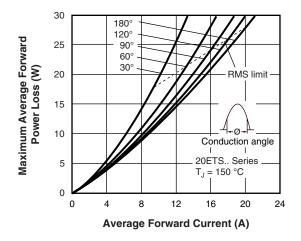


Fig. 3 - Forward Power Loss Characteristics

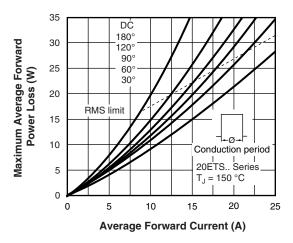
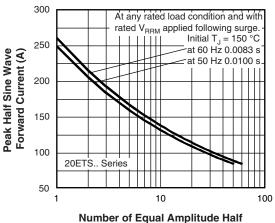


Fig. 4 - Forward Power Loss Characteristics



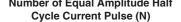


Fig. 5 - Maximum Non-Repetitive Surge Current

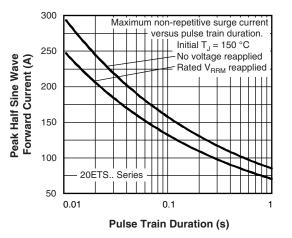


Fig. 6 - Maximum Non-Repetitive Surge Current

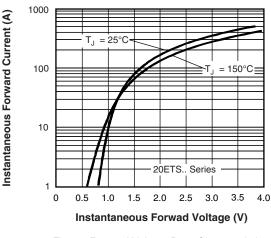


Fig. 7 - Forward Voltage Drop Characteristics



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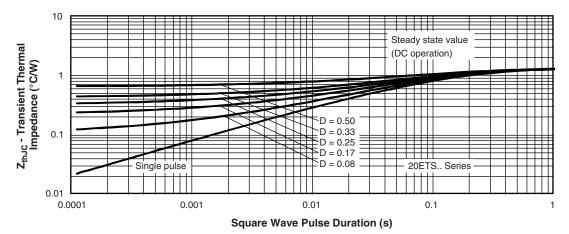
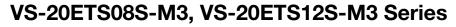


Fig. 8 - Thermal Impedance Z_{thJC} Characteristics

ORDERING INFORMATION TABLE

Device code	vs-	20	Е	т	S	12	S	TRL	-M3
		2	3	4	5	6	(7)	8	9
	1 · 2 · 3 ·	- Cur	nay Sem rent rati cuit conf	ng (20 =	= 20 A)	oduct			
	4	E • Pac	= single kage: = D ² PA)					
	5 - 6 -	S	e of silic = stand tage coo	ard reco	-			08 = 8	
	7 - 8 -	S = • No	surface one = tu	mounta be	ible		1)	12 = 1	200 V
	9.	• TF	RL = tap RR = tap s = halog	e and r	eel (righ	nt oriente	ed)	termina	ations le



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ORDERING INFORMATION (Example)							
PREFERRED P/N	BASE QUANTITY	PACKAGING DESCRIPTION					
VS-20ETS08S-M3	50	Antistatic plastic tube					
VS-20ETS08STRR-M3	800	13" diameter reel					
VS-20ETS08STRL-M3	800	13" diameter reel					
VS-20ETS12S-M3	50	Antistatic plastic tube					
VS-20ETS12STRR-M3	800	13" diameter reel					
VS-20ETS12STRL-M3	800	13" diameter reel					

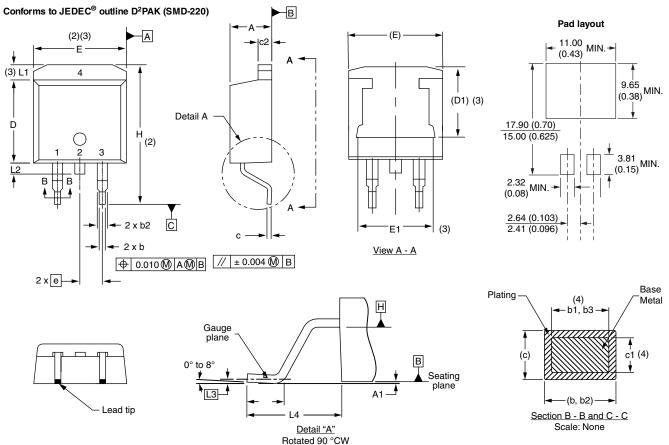
LINKS TO RELATED DOCUMENTS					
Dimensions	www.vishay.com/doc?96164				
Part marking information	www.vishay.com/doc?95444				
Packaging information	www.vishay.com/doc?96424				
SPICE model	www.vishay.com/doc?95409				



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D²PAK

DIMENSIONS in millimeters and inches





SYMBOL	MILLIM	IETERS	INC	HES	NOTES	
STMBOL	MIN.	MAX.	MIN.	MAX.	NOTES	
A	4.06	4.83	0.160	0.190		
A1	0.00	0.254	0.000	0.010		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
с	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	

SYMBOL	MILLIMETERS		INCHES		NOTES
STNIDUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
E	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100) BSC	
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5 M-1994

(2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body

⁽³⁾ Thermal pad contour optional within dimension E, L1, D1 and E1

⁽⁴⁾ Dimension b1 and c1 apply to base metal only

⁽⁵⁾ Datum A and B to be determined at datum plane H

⁽⁶⁾ Controlling dimension: inches

⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-263AB

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